

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

h re Application of:	) : Examiner: S. Isaac
MASATAKA ITO	)
Application No.: 10/091,461	: Group Art Unit: 2812
Filed: March 7, 2002	j
For: SOI SUBSTRATE, ANNEALING METHOD THEREFOR, SEMICONDUCTOR DEVICE HAVING THE SOI SUBSTRATE, AND METHOD OF MANUFACTURING THE SAME	) : ) : ) : ) : ) : Date: February 20, 2004
SAIVIE	: Date: February 20, 2004

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## **LETTER TRANSMITTING FORMAL DRAWINGS**

Sir:

Transmitted herewith are 2 sheets of formal drawings to be substituted for the corresponding drawing sheets presently on file in the above-identified application.

In the drawings, reference numeral (8) has been changed to (7), for consistency with the specification.

I hereby certify that this correspor United States Postal Service as first- to: Commissioner for Patents, P.O. 1450 on	class mail in an envelope addressed
February 20, 2004	
(Date of Dep	
George K. Ng, Reg. N	
(Name of Attorney fo	r Applicant)
Stone L. My	February 20, 2004
Signature	Date of Signature
// //	
V	

Applicants' undersigned attorney may be reached in our Costa Mesa, California office by telephone at (714) 540-8700. All correspondence should continue to be directed to our address given below.

Respectfully submitted,

Registration No. 54 334

FITZPATRICK, CELLA, HARPER & SCINTO 30 Rockefeller Plaza New York, New York 10112-3800 Facsimile: (212) 218-2200

CA\_MAIN 77411v1